

**Pb Free Plating Product**

# SFF15A60U



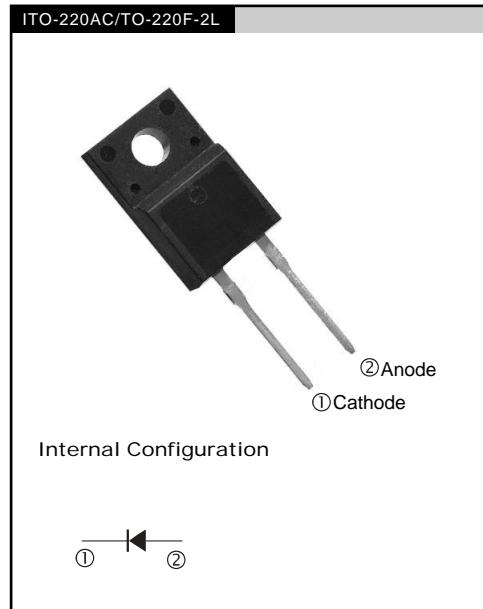
15Amperes,600Volts Insulated Hyper Fast Soft Recovery Epitaxial Diode

## APPLICATION

- Freewheeling, Snubber, Clamp
- Inversion Welder
- PFC
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- UPS

## PRODUCT FEATURE

- Ultrafast Recovery Time
- Soft Recovery Characteristics
- 175 °C Operating Junction Temperature
- Low Forward Voltage
- High Surge Current Capability
- Low Leakage Current



## GENERAL DESCRIPTION

SFF15A60U using the lastest FRED FAB process(planar passivation pellet) with ultrafast and soft recovery characteristics.

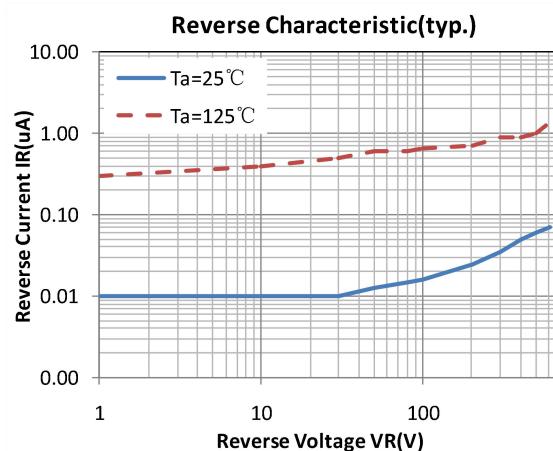
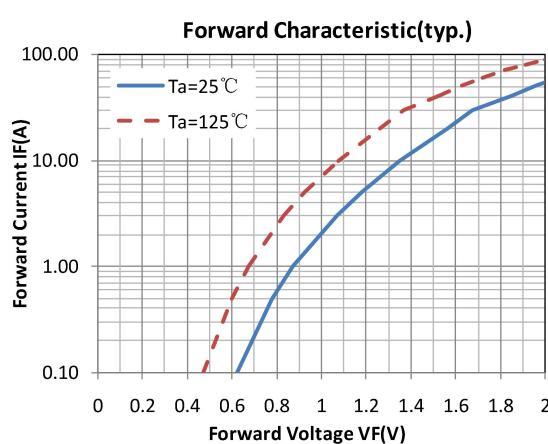
<b>Absolute Maximum Ratings</b>				
Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	V <sub>RRM</sub>		600	V
Continuous forward current	I <sub>F(AV)</sub>	T <sub>c</sub> =110°C	15	A
Single pulse forward current	I <sub>FSM</sub>	T <sub>c</sub> =25°C	120	
Maximum repetitive forward current	I <sub>FRM</sub>	Square wave, 20kHz	30	°C
Operating junction	T <sub>j</sub>		175	
Storage temperatures	T <sub>stg</sub>		-55 to +175	°C

**Electrical characteristics (Ta=25°C unless otherwise specified)**

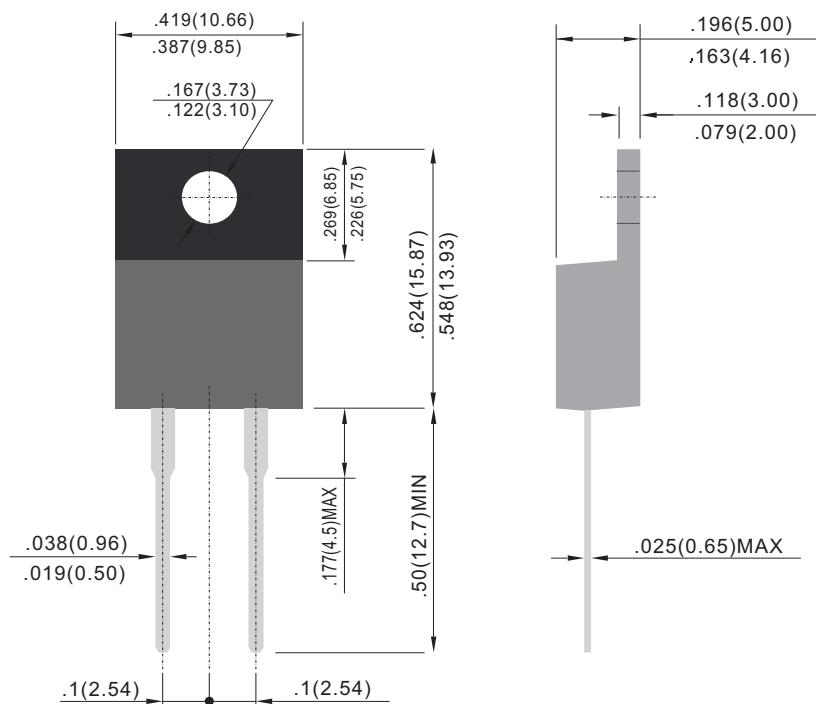
Parameter	Symbol	Test Conditions	Min	Typ.	Max.	Units
Breakdown voltage Blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> =100μA	600			
Forward voltage (Per Diode)	V <sub>F</sub>	I <sub>F</sub> =15A		1.35	1.60	V
		I <sub>F</sub> =15A, T <sub>j</sub> =125°C		1.20	1.40	
Reverse leakage current(Per Diode)	I <sub>R</sub>	V <sub>R</sub> = V <sub>RRM</sub>			20	μA
		T <sub>j</sub> =150°C, V <sub>R</sub> =600V			200	
Reverse recovery time(Per Diode)	t <sub>rr</sub>	I <sub>F</sub> =0.5A, I <sub>R</sub> =1A, I <sub>RR</sub> =0.25A		28	35	ns
		I <sub>F</sub> =1A, V <sub>R</sub> =30V, di/dt =200A/us		22	25	

**Thermal characteristics**

Paramter	Symbol	Typ	Units
Junction-to-Case	R <sub>θJC</sub>	3.0	°C/W

**Electrical performance (typic)**

## ITO-220AC/TO-220F-2L Package Outline:



Unit : inch (mm)